

# Using defects to create ceramics with giant permittivity as ultracapacitors

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## Abstract

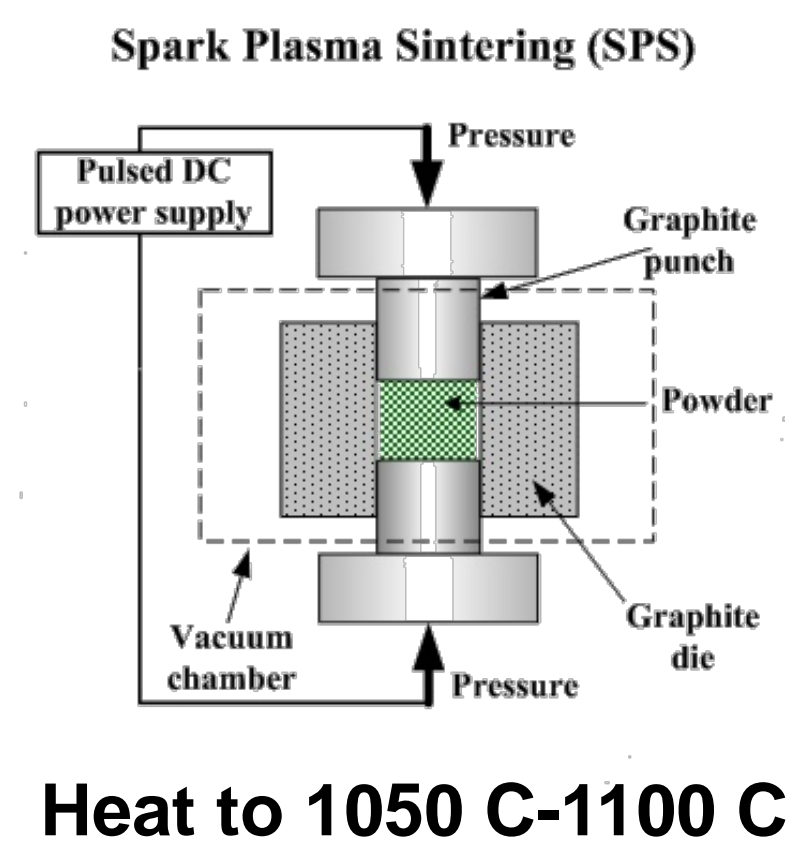
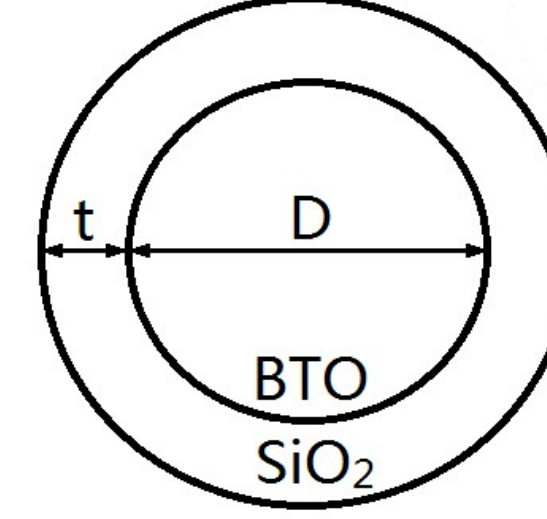
Dielectrics with a high and weakly-temperature-dependent permittivity are highly desirable for the development of high performance energy storage devices. It is well known that ferroelectrics (FEs) exhibit a high permittivity that is strongly dependent on the temperature due to phase transition. In this project, the FE BaTiO<sub>3</sub> (BTO), based ceramics are developed as ultra-capacitors by introducing defects to eliminate the phase transition and enhance the permittivity. The ceramics are fabricated using a unique process: BTO nanoparticles are coated with a nano-layer of SiO<sub>2</sub> and, then, sintered in vacuum using SPS process. The ceramics exhibit a giant permittivity and many other unique properties.

## Fabrication

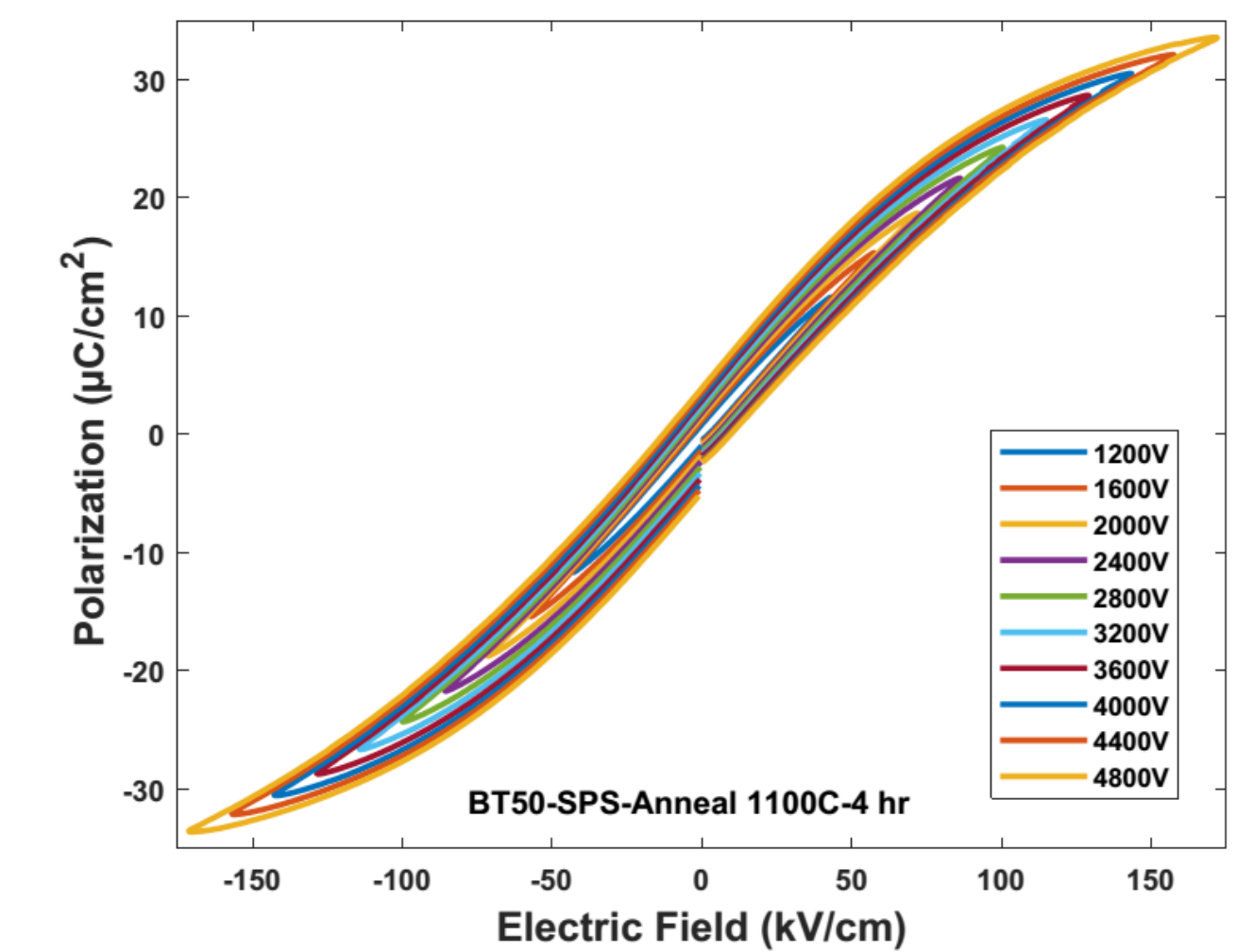
Vacuum Treatment:  
 Inducing Defects  
 (Oxygen Vacancy)



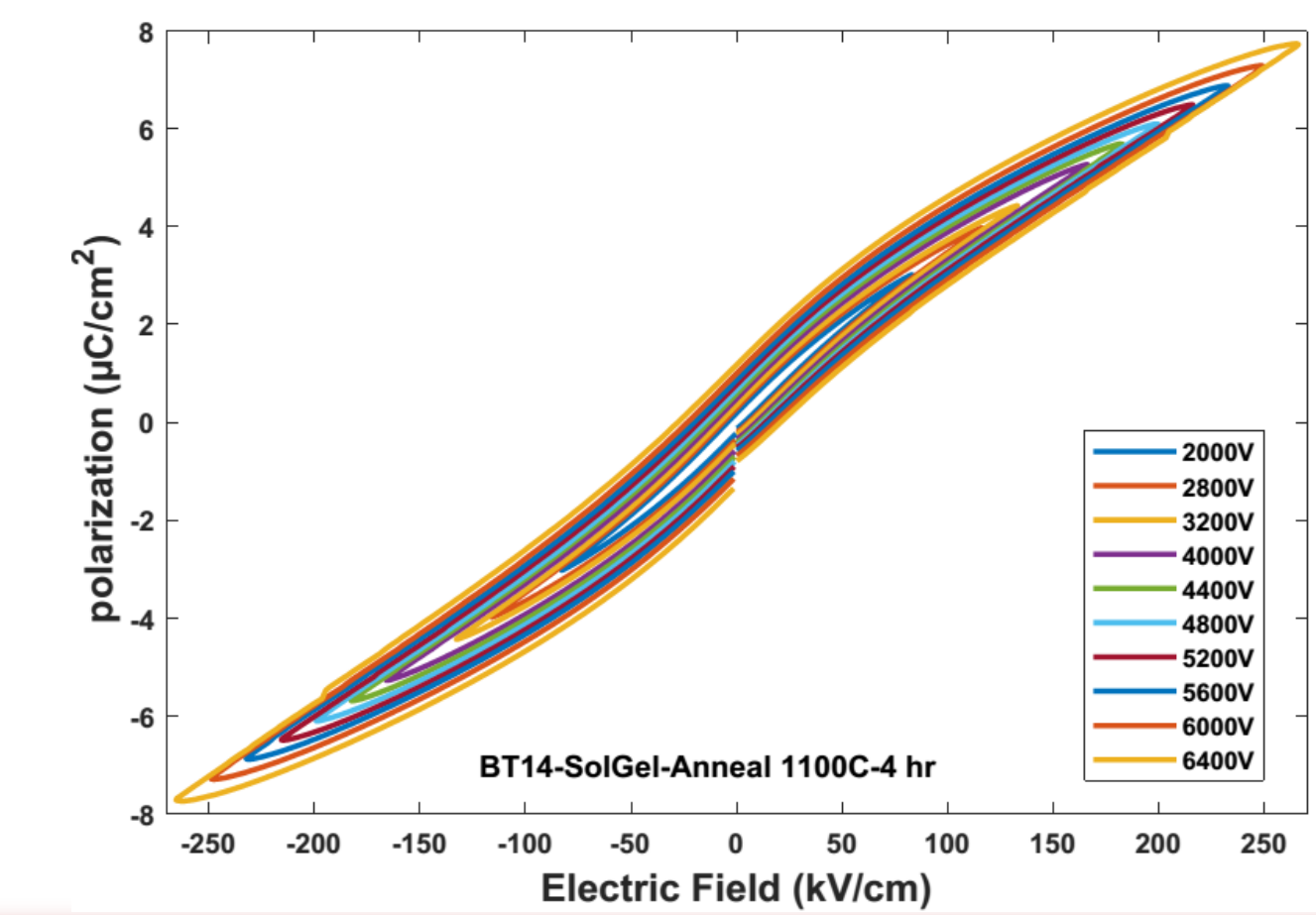
Sol-Gel  
 Chemical Coating of BTO powder  
 $\text{Si}(\text{OC}_2\text{H}_5)_4 + \text{H}_2\text{O} \rightarrow \text{SiO}_2 + \text{C}_2\text{H}_5\text{OH}$



## P-E Loop



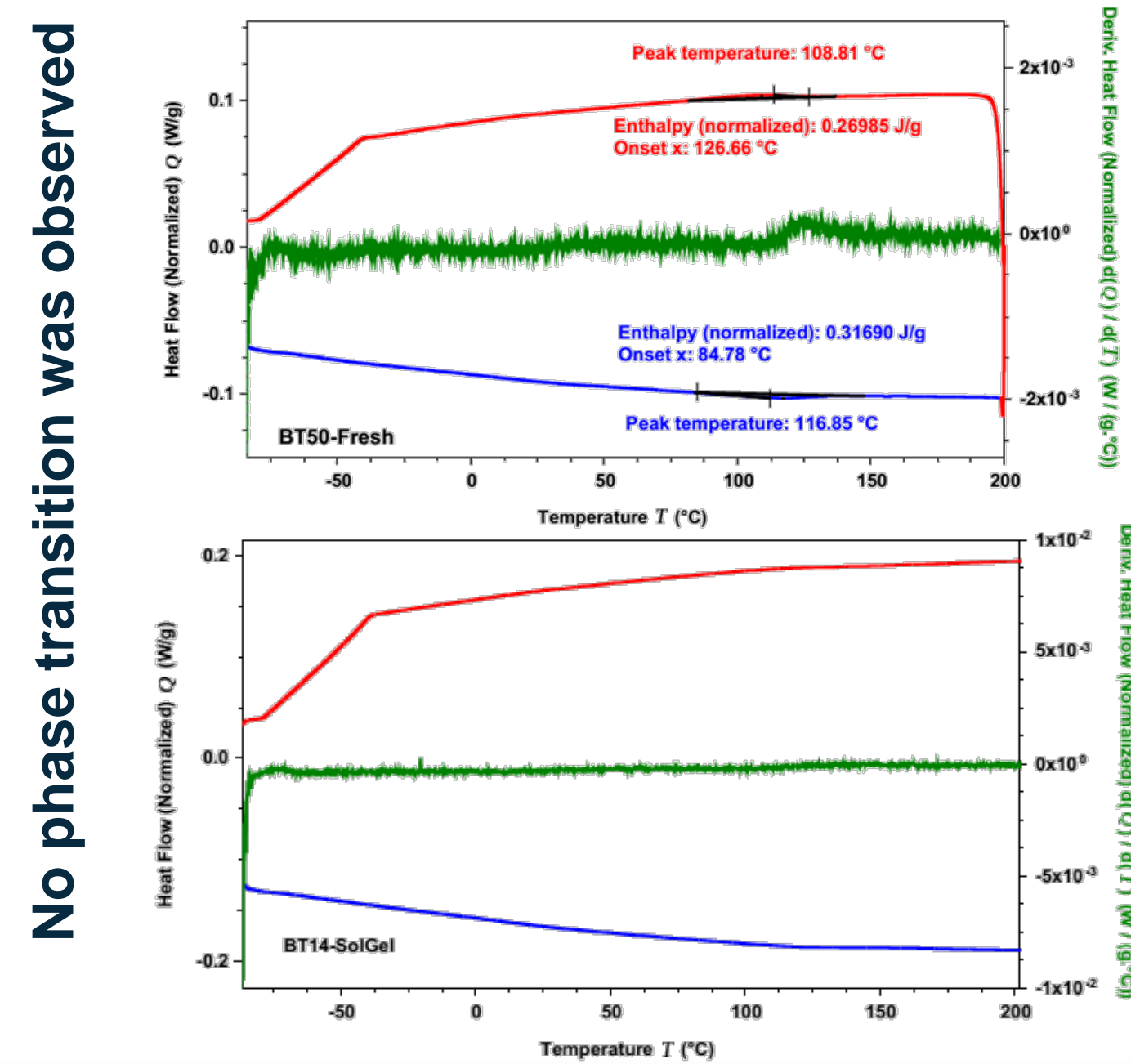
→ High polarization  
 → High electrical breakdown field up to 27 MV/m



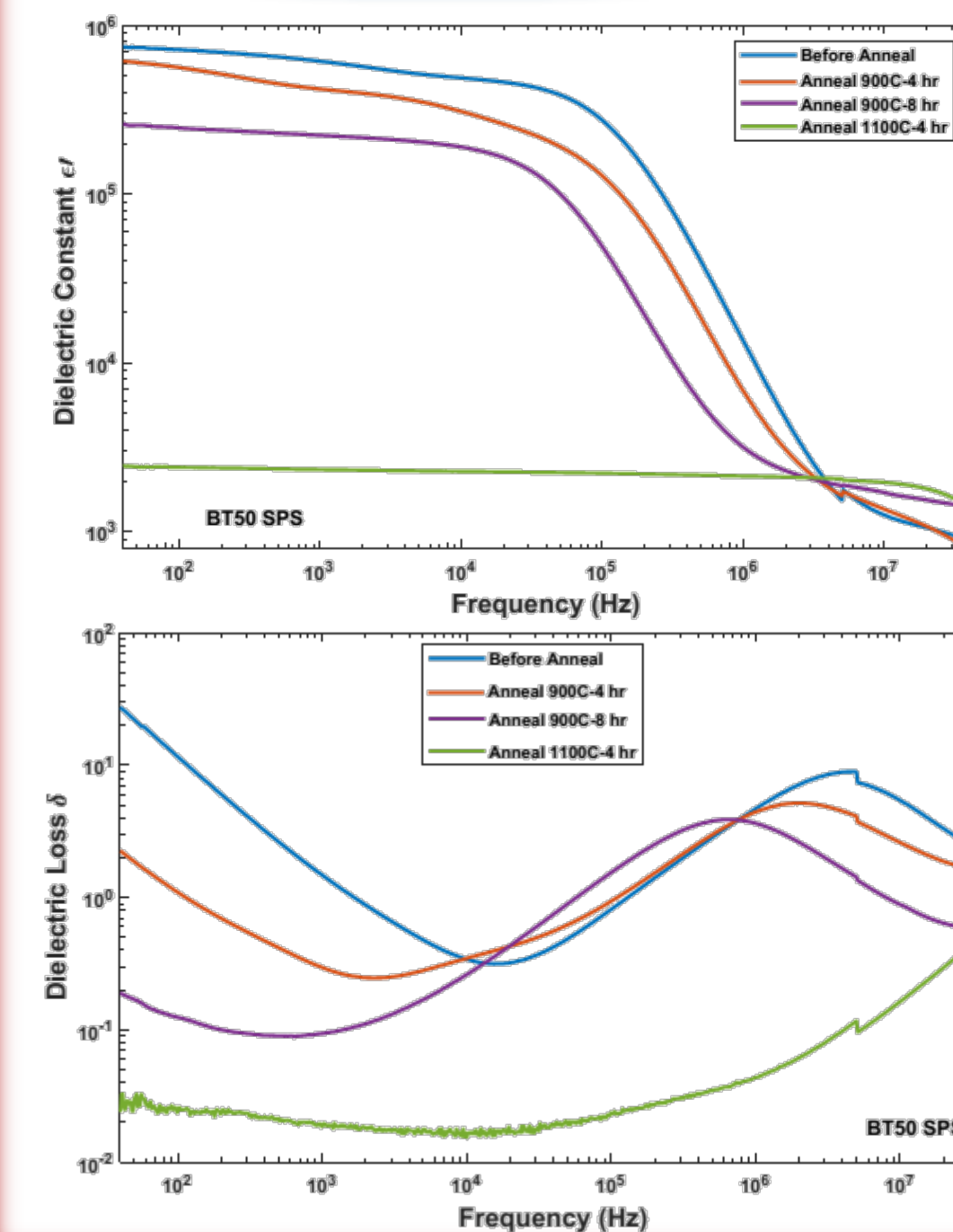
→ High energy density of > 3 J/cm<sup>3</sup>  
 → High efficiency

## DSC

Temperature independency



## Dielectric behavior



Giant permittivity directly determined by fabrication condition

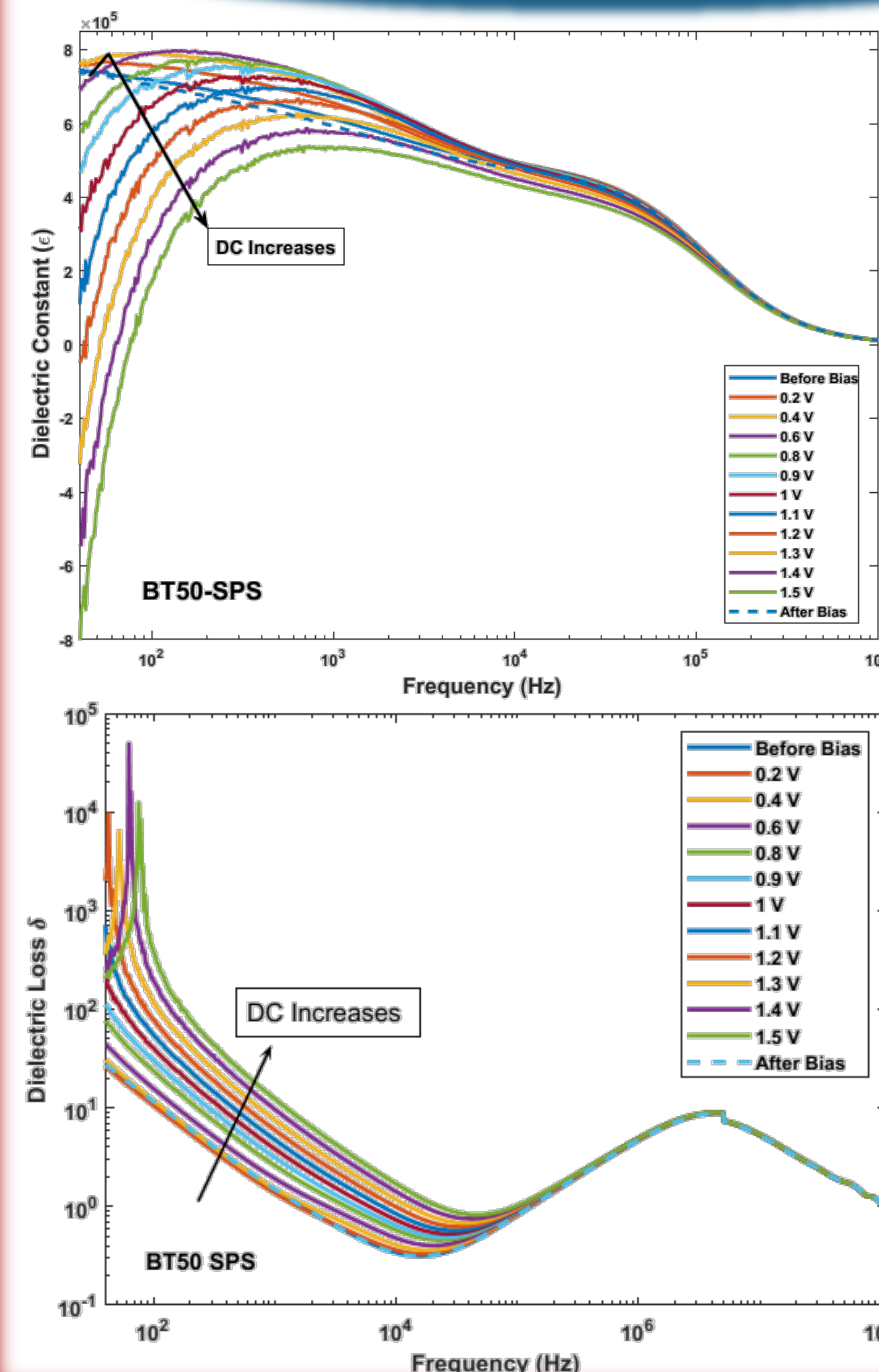
Acceptable Loss

## Motivation

Today & Future Demands



## DC Bias Effect



→ Tunable permittivity with a giant tunability

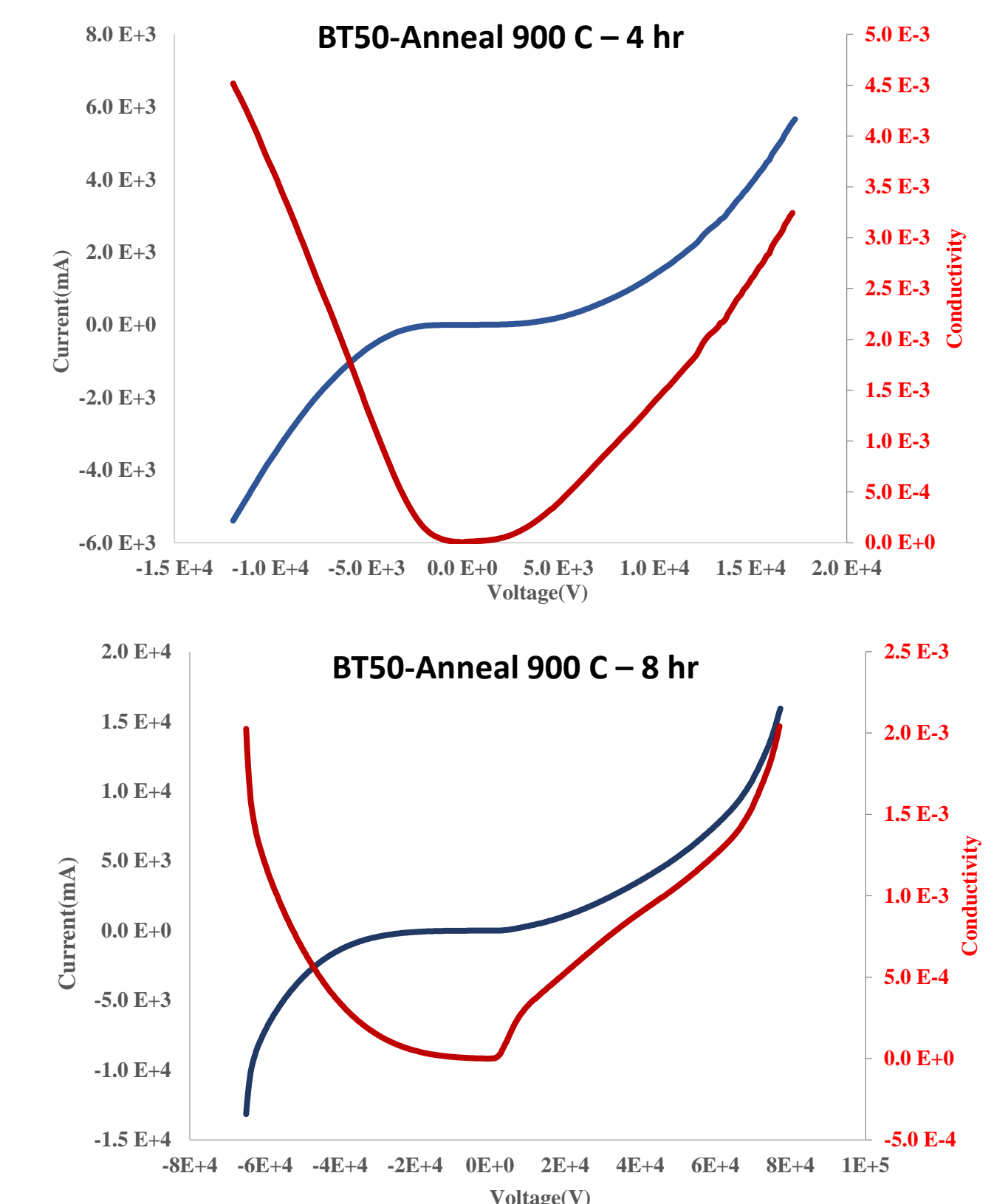
The permittivity can be tuned from ~ 10<sup>5</sup> to ~ -10<sup>5</sup> even -10<sup>6</sup>

→ Negative permittivity with a low plasma frequency

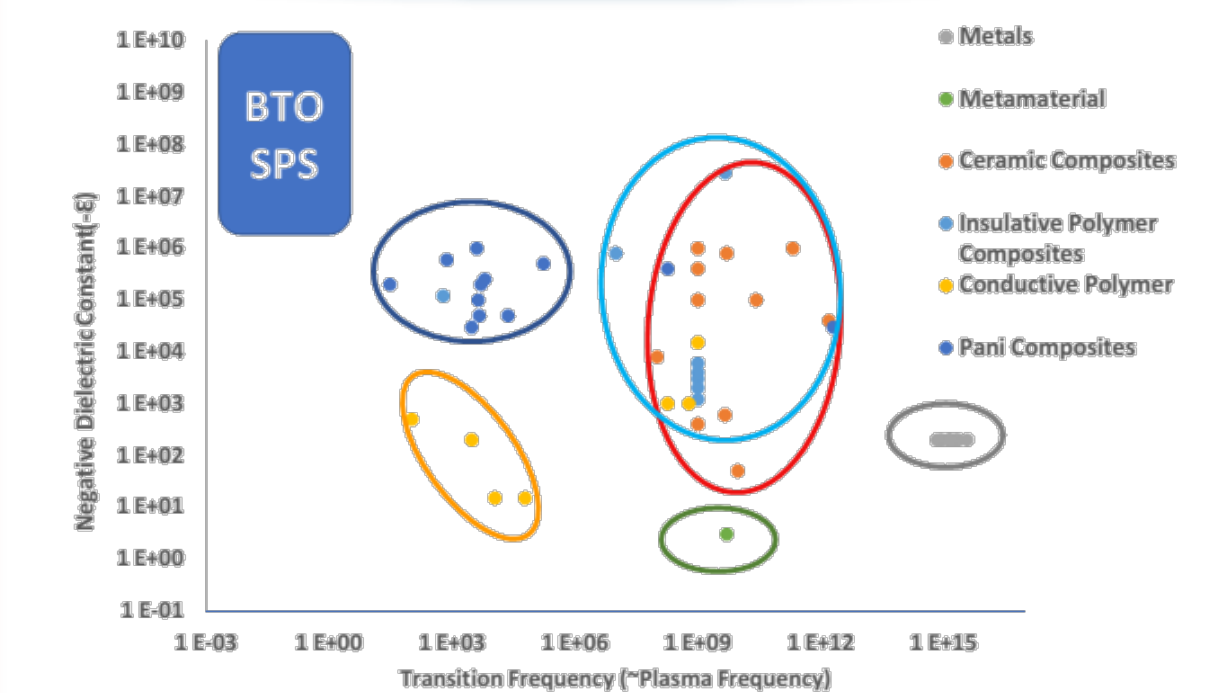
A new mechanism!

## Thermal Annealing & I-V Curve

Nonhomogeneous structure p-n junction behavior



## Achievement



Unique Material Properties

## Conclusion

- The unique processes developed in this project can be used to fabricate the ultra-capacitors and dielectric materials, such as
1. Ultra-capacitor with High energy density with a high efficiency
  2. Ultra-capacitors exhibit a giant permittivity (up to 10<sup>6</sup>)
  - 3- Permittivity exhibits a giant tunability > 100%
  4. Giant negative permittivity with a low plasma frequency
  5. p-n junction like behavior in a ceramic sample.

## Future Work

- Optimize the process to maximize properties for different applications
- Fundamental understanding of the unique and abnormal properties observed in the ceramics.

## Objective

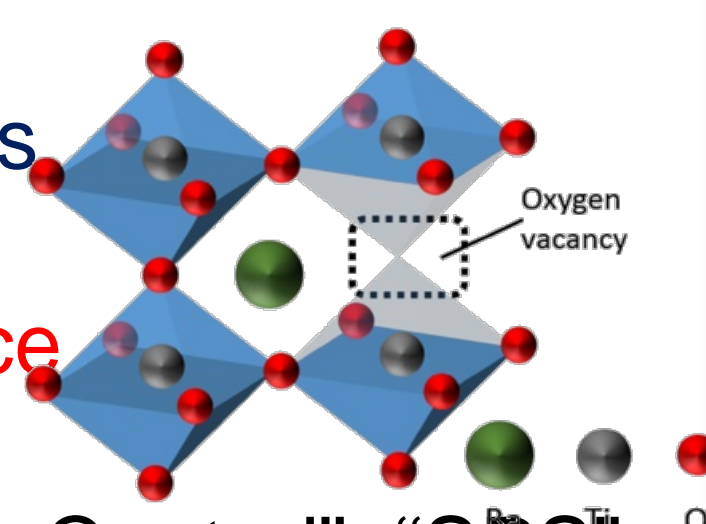
BTO

Ferroelectric properties

Temperature dependence

“Vacuum Treated”, “SiO<sub>2</sub> Coated”, “SPS”

- Giant permittivity and high energy density with good stability
- Negative Permittivity with a low Plasma Freq



## Acknowledgement

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